



40V PNP MEDIUM POWER TRANSISTOR IN SOT23

Features

- BV_{CEO} > -40V
- BV_{ECO} > -3V
- I_C = -3A Continuous Collector Current
- V_{CE(sat)} < -85mV @ -1A
- R_{CE(sat)} = 55mΩ typical
- P_D = 1.25W
- High Power Dissipation SOT23 Package
- High Peak Current
- Low Saturation Voltage
- 3V Reverse Blocking Voltage
- Complementary Part Number: ZXTN25040DFH
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

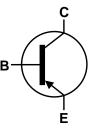
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)

Applications

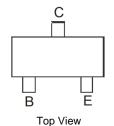
- MOSFET and IGBT gate driving
- DC-DC converters
- Motor drives
- High-side drivers



Top View



Device Symbol



Pin-Out

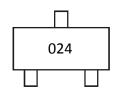
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP25040DFHTA	024	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



024 = Product Type Marking Code



Absolute Maximum Ratings @ TA = +25°C, unless otherwise specified.

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-45	V
Collector-Emitter Voltage (Forward Blocking)	V _{CEO}	-40	V
Emitter-collector voltage (Reverse Blocking)	V_{ECO}	-3	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-3	Α
Peak Pulse Current	I _{CM}	-9	A

Thermal Characteristics @ $T_A = +25$ °C unless otherwise specified

Characteristic	Symbol	Value	Unit		
	(Note 5)		0.73		
	(11010-0)		5.84		
	(Note 6)		0.78		
	(14010-0)		6.24		
Power Dissipation	(Note 7)	P_{D}	1.05	W	
Linear derating factor	(Note 1)	ט י	8.4	mW/°C	
	(Note 8)		1.25		
			9.6		
	(Note 9)		1.81		
	(14016-9)		14.5		
	(Note 5)		171		
	(Note 6)		160		
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	119	°C/W	
	(Note 8)		100		
	(Note 9)		69		
Thermal Resistance, Junction to Lead	(Note 10)	$R_{ heta JL}$	74.95	°C/W	
Thermal Resistance, Junction to Case	(Note 11)	R _θ JC	45	°C/W	
Operating and Storage Temperature Range —		$T_{J_i}T_{STG}$	T _J , T _{STG} -55 to +150		

- 5. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Same as note (5), except the device is mounted on FR4 substrate PCB layout with minimum recommended pad layout.
- 7. Same as note (5), except the device is surface mounted on 25mm x 25mm with 2 oz copper. 8. Same as note (5), except the device is surface mounted on 50mm x 50mm with 2 oz copper.

- 9. Same as note (8), except the device is measured at t<5secs.

 10. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 11. Thermal resistance from junction to the top of the case.

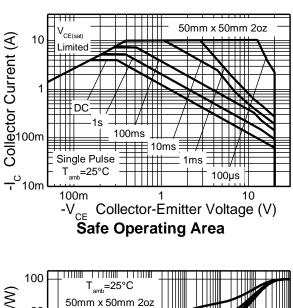
ESD Ratings (Note 12)

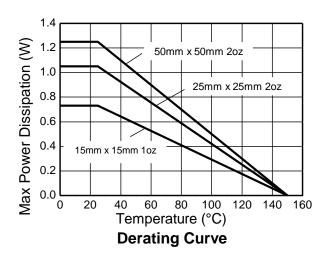
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

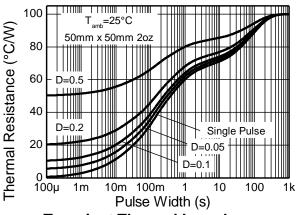
12. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Note:

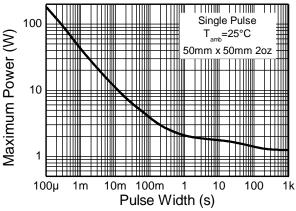


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation



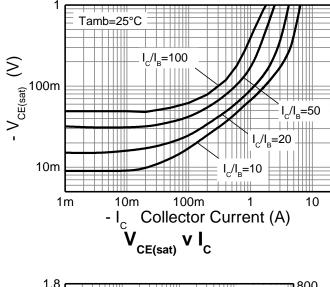
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

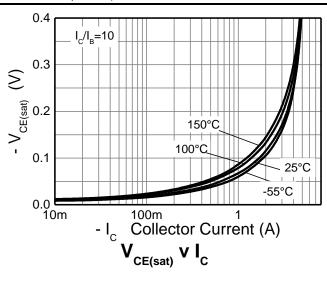
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-45	-75	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 13)	BV _{CEO}	-40	-65	-	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.2	-	V	$I_E = -100 \mu A$
Emitter-Collector Breakdown Voltage	BV _{ECO}	-3	-8.7	-	V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I _{CBO}	-	< -1	-50	nA	V _{CB} = -45V
Collector-Base Cutoff Current		-	-	-0.5	μΑ	$V_{CB} = -45V, T_{amb} = +100^{\circ}C$
Emitter-Base Cutoff Current	I _{EBO}	-	< -1	-50	nA	V _{EB} = -5.6V
		300	450	900		I _C = -10mA, V _{CE} = -2V
Static Forward Current Transfer Ratio (Note 13)	h _{FE}	200	300	-	-	I _C = -1A, V _{CE} = -2V
		30	60	-		$I_C = -3A$, $V_{CE} = -2V$
		-	-170	-260		$I_C = -1A$, $I_B = -20mA$
Collector-Emitter Saturation Voltage (Note 13)	V _{CE(sat)}	-	-65	-85	mV	$I_C = -1A$, $I_B = -100mA$
		-	-165	-220		$I_C = -3A$, $I_B = -300mA$
Base-Emitter Saturation Voltage (Note 13)	V _{BE(sat)}	-	-930	-1000	mV	I _C = -3A, I _B = -300mA
Base-Emitter Saturation Voltage (Note 13)	V _{BE(on)}	-	-830	-900	mV	$I_{C} = -3A$, $V_{CE} = -2V$
Output Capacitance	C _{obo}	-	17.4		pF	V _{CB} = -10V, f = 1MHz
Transition Frequency	f⊤	-	270	-	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Turn-on Time	t _(on)	-	75.5	-	ns	V _{CC} = -15V, I _C = -750mA,
Turn-off Time	t _(off)	-	320	-	ns	$I_{B1} = -I_{B2} = -15\text{mA}$

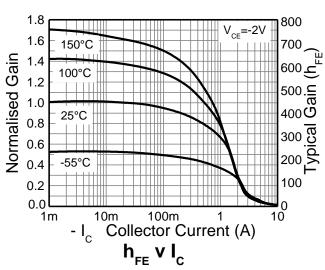
Note: 13. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

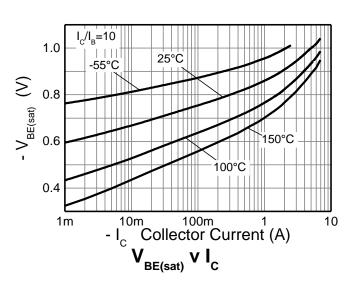


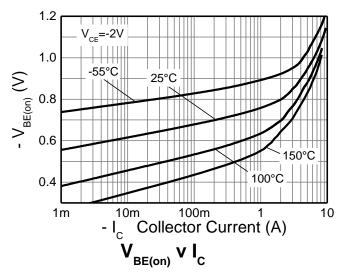
Typical Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)









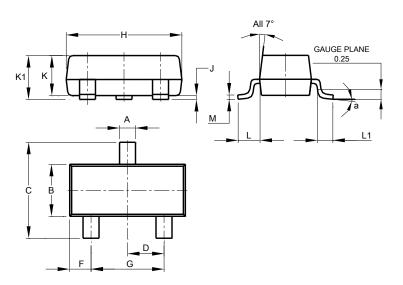




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

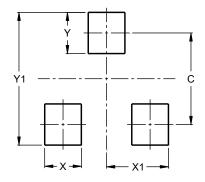


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
H	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K 1	0.903	1.10	1.025		
١	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	29			



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